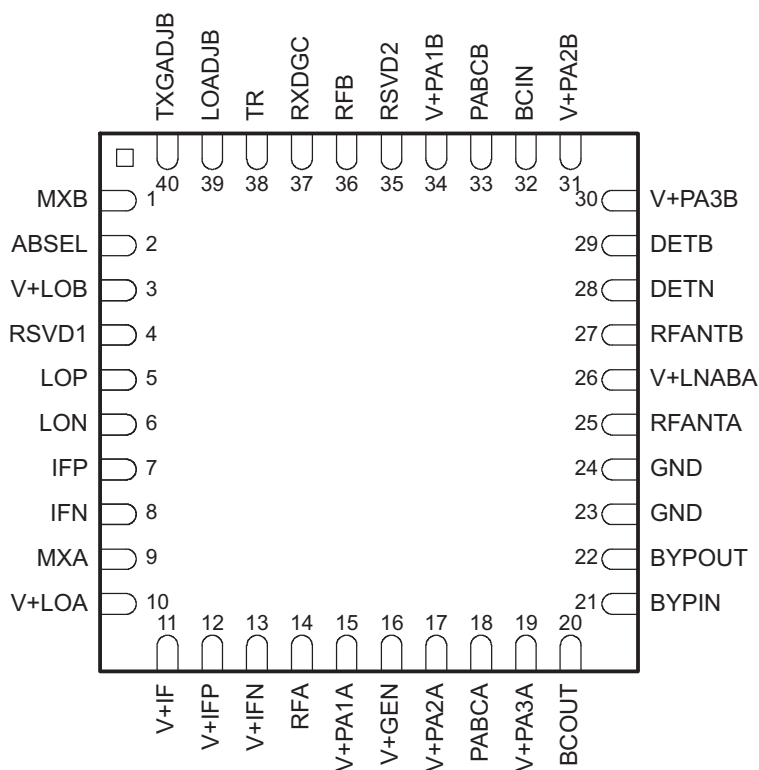


High-Power Dual-Band (2.4-GHz to 2.5-GHz and 4.9-GHz to 5.9-GHz) RF Front-End

FEATURES

- Highly Integrated 802.16 d/e Radio Frequency Front End ASIC
- Fully Integrated Up/Down Converters, LNAs, PAs and T/R Switches
- Super Heterodyne Architecture for Superior Adjacent Channel Rejection Performance
- Differential LO and IF Interface for Enhanced Spurious/EMI Performance
- Common Frequency Plan uses a Single LO and Common IF for Single IF Filter for Both Bands
- Integrated Temperature Compensated TX Power Detectors
- PA Bias Control Function
- Antenna Port $OP_{1dB} = +23$ dBm Typical
- Antenna Port $OIP3 = +33$ dBm, Typical
- Frequency Range: 2.4 to 2.5 and 4.9 to 5.9 GHz
- Noise Figure: 4 dB ISM Band, 6 dB 5 GHz Bands Typical
- Typical Gain: 38 dB TX, 20 dB RX
- IF = 374 MHz

TRF2436 PACKAGE
(TOP VIEW)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



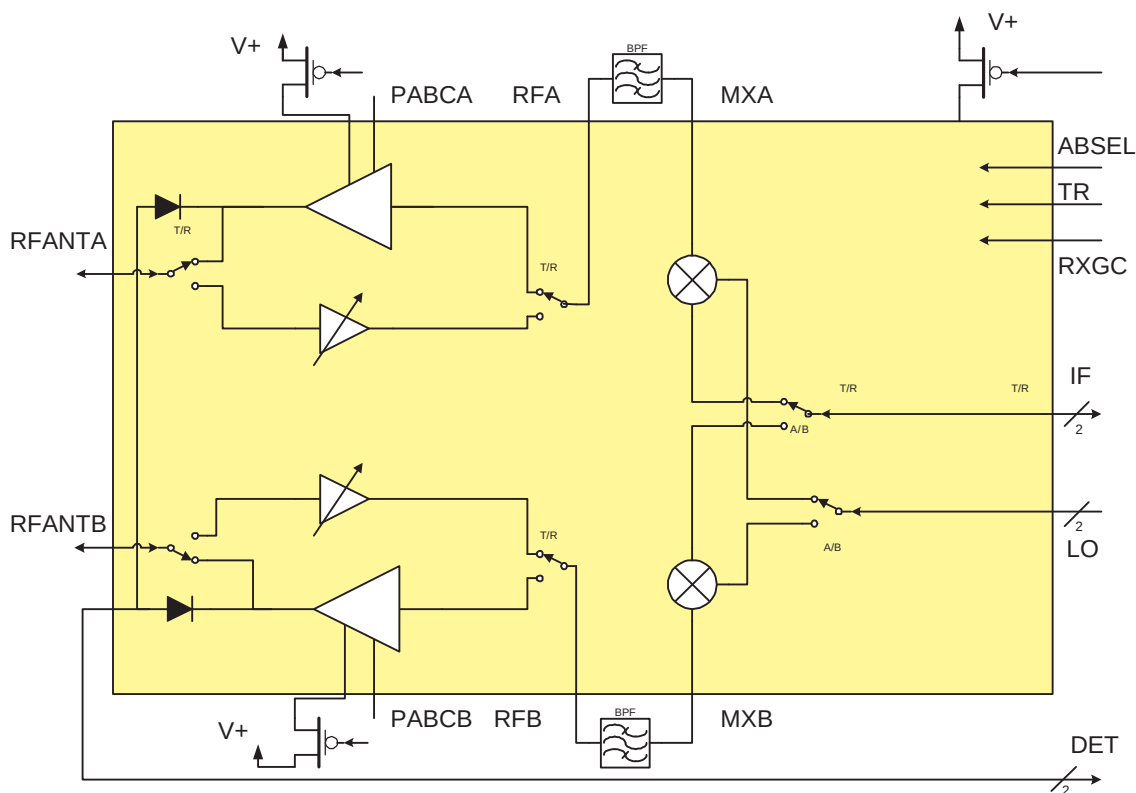
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION

The TRF2436 is a fully integrated Dual Band Tri Mode Radio Frequency Front End (RFFE) designed specifically for use in 802.16 d/e applications. The TRF2436 is designed to perform RF up and down conversions in the unlicensed ISM and 4.9-5.9 GHz bands. The TRF2436 uses a common IF frequency for both bands, eliminating the need for additional IF filtering. Combined with the TI TRF2432 IF/IQ Transceiver/Synthesizer, the TRF2436 completes the TI WLAN two-chip radio.

The TRF2436 incorporates all of the RF blocks for both the “b” and “a” bands except for low cost ceramic filters. The ASIC includes LNAs, PAs, mixers, bias circuitry, RX gain control, transmit coupler detectors, and T/R switches. High integration and internal RF matching enhances performance and greatly reduce external part count. The only external components needed (other than simple passives) for operation are RF filters and external low power DC switching FETs.

Functional Block Diagram



DEVICE INFORMATION

TERMINAL FUNCTIONS

TERMINAL		I/O	TYPE	DESCRIPTION
NAME	NO.			
MXB	1	I/O	RF SE	B band RF Input/Output to mixer. 50-Ω single ended. Do not apply DC.
ABSEL	2	I	Digital	Band select pin. HIGH = A-band. LOW = B-band.
V+LOB	3	I	Power	B band LO amplifier bias +3.3V
RSVD1	4	-	-	Not connected for normal operation. Leave Open.
LOP	5	I	RF Dif.	LO input (differential) Positive, AC coupled

DEVICE INFORMATION (continued)
TERMINAL FUNCTIONS (continued)

TERMINAL		I/O	TYPE	DESCRIPTION
NAME	NO.			
LON	6	I	RF Dif.	LO input (differential) Negative, AC coupled
IFP	7	I/O	RF Dif.	IF input/output (differential) Positive, DC coupled, typical DC Voltage is 2.6V
IFN	8	I/O	RF Dif.	IF input/output(differential) Negative, DC coupled, typical DC Voltage is 2.6V
MXA	9	I/O	RF SE	A band RF Input/Output to mixer. 50-Ω single ended. Do not apply DC.
V+LOA	10	I	Power	A band LO amplifier bias +3.3V
V+IF	11	I	Power	IF amplifier bias +3.3V.
V+IFP	12	I	Power	IFP amplifier bias +3.3V.
V+IFN	13	I	Power	IFN amplifier bias +3.3V.
RFA	14	I/O	RF SE	A Band RF Input/Output to PA/LNA. 50-Ω single ended. AC coupled.
V+PA1A	15	I	Power	A band Power amplifier bias +3.3V.
V+GEN	16	I	Power	DC Bias Control Bias +3.3V.
V+PA2A	17	I	Power	A band Power amplifier bias +3.3V.
PABCA	18	-	-	A band PA Bias Control Input
V+PA3A	19	-	-	A band Power amplifier bias +3.3V.
BCOUT	20	O	Analog	Bias Control Output.
BYPIN	21	I	Analog	DC Bias Bypass Input
BYPOUT	22	O	Analog	DC Bias Bypass Output
GND	23, 24	-	-	Connect to ground
RFANTA	25	I/O	RF SE	A band RF in/out to antennas. AC coupled.
V+LNABA	26	I	Power	A and B Band LNA bias +3.3V.
RFANTB	27	I/O	RF SE	B band RF in/out to antennas. AC coupled.
DETN	28	O	Analog	Negative RF power detector output
DETP	29	O	Analog	Positive RF power detector output.
V+PA3B	30	I	Power	B band Power amplifier bias +3.3V.
V+PA2B	31	I	Power	B band Power amplifier bias +3.3V.
BCIN	32	I	Analog	Bias control input
PABCB	33	-	-	B band PA Bias Control Input
V+PA1B	34	I	Power	B band Power amplifier bias +3.3V.
RSVD2	35	-	-	Not Connected for normal operation. Leave Open.
RFB	36	I/O	RF SE	B band RF Input/Output to PA/LNA. 50-Ω single ended. AC coupled.
RXDGC	37	I	Digital	Rx Gain Control. HIGH = minimum gain. LOW = maximum gain
TR	38	I	Digital	Transmit/Receive mode control. HIGH = transmit. LOW = receive.
LOADJB	39	-	-	Not connected for normal operation. Leave Open. B band LO amp bias adjust.
TXGADJB	40	-	-	Not connected for normal operation. Leave open. PAB Amplifier bias adjust.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)

			VALUE	UNIT
V_{CC}	DC supply voltage		0 to 6.9	V
I_{CC}	DC supply current		600	mA
	RF input power	Any port and any mode	10	dBm
V_{ID}	Digital input voltage		-0.3 to 5	V
T_{JC}	Junction temperature		175	°C
θ_{JC}	Thermal resistance junction-to-case		35	°C/W
T_A	Operating temperature		-20 to 85	°C
T_{stg}	Storage temperature		-40 to 105	°C
	Lead temperature	40 sec maximum	220	°C

DC CHARACTERISTICSTYP ratings are at 25°C and $V_{CC} = 3.3$ V, MIN and MAX ratings are over operating free-air temperature and voltage ranges (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage	2.7	3.3	4.2	V
I_{CC}	Total supply current	B Band, RX Mode	65	105	mA
		A Band, RX Mode	80	120	mA
		B Band, TX Mode, Max PABC input	410	520	mA
		A Band, TX Mode, Max PABC input	450	550	mA
V_{IH}	High-level input voltage	1.7			V
V_{IL}	Low-level input voltage			0.5	V
I_{IH}	High-level input current		100	300	μA
I_{IL}	Low-level input current			-50	μA

RECEIVER CHARACTERISTICSTR = Low, 2 dB base band filter loss in RX band, MIN, TYP, and MAX rating are at 25°C and $V_{CC} = 3.3$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{IRF}	RF input frequency	B band		2500	MHz
		A band		5900	
f_{LO}	LO input frequency	B band		2874	MHz
		A band		3137	
f_{IF}	IF input frequency		374		MHz
G	Gain	B Band High Gain Mode RXGC=LOW	17	19	dB
		A Band High Gain Mode RXGC=LOW	18	23	
ΔG	Gain step size	B Band Low Gain Mode RXGC=HIGH		25	dB
		A Band Low Gain Mode RXGC=HIGH		15	
	Noise figure	B Band. Max Gain	4	5	dB
		A Band. Max Gain	6	7.5	

RECEIVER CHARACTERISTICS (continued)

TR = Low, 2 dB base band filter loss in RX band, MIN, TYP, and MAX rating are at 25°C and $V_{CC} = 3.3$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input P_{-1dB}		B Band High Gain Mode RXGC=LOW	-16	-13		dBm
		B Band Low Gain Mode RXGC=HIGH				
		A Band High Gain Mode RXGC=LOW	-22	-18		
		A Band Low Gain Mode RXGC=HIGH	-16	-13		
Input 3rd order intercept point		B Band High Gain Mode RXGC=LOW	-6	-2		dBm
		B Band Low Gain Mode RXGC=HIGH	4	8		
		A Band High Gain Mode RXGC=LOW	-12	-8		
		A Band Low Gain Mode RXGC=HIGH	-6	-3		
RF input return loss		Z = 50 Ω Both Bands, Both Gain modes	8			dB
LNA out return loss RF		Z = 50 Ω Both Bands, Both Gain modes	9			dB
Mixer input MX return loss		Z = 50 Ω Both Bands	10			dB
Output return loss		Measured into 200 Ω differential	10			dB
LO at MX leakage		B band		-30		dBm
		A Band (5274-6274 MHz)		-30		
LO at IF leakage		Both bands		-40		dBm
Gain flatness full band		B band		1		dB
		A band		2		
Gain flatness / 22 MHz		Both bands				dB
Gain settling time		Full range to within 0.5 dB final. All bands		0.3		μ s
RF to RFANT isolation		In Band: B Band High Gain Mode RXGC=LOW		30		dB
		In Band: B Band Low Gain Mode RXGC=HIGH		5		
		In Band: A Band High Gain Mode RXGC=LOW		25		
		In Band: A Band Low Gain Mode RXGC=HIGH		35		

TRANSMITTER CHARACTERISTICS

TR = High, 2 dB base band filter loss in RX band, MIN, TYP, and MAX rating are at 25°C and $V_{CC} = 3.3$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{IF}	IF input frequency			374		MHz
f_{ORF}	RF output frequency	B band	2400		2500	MHz
		A band	4900		5900	MHz
f_{LO}	LO input frequency	B band	2774		2874	MHz
		A band	2637		3137	MHz
G	Gain	B Band	37	40		dB
		A Band	40	43		dB

TRANSMITTER CHARACTERISTICS (continued)

TR = High, 2 dB base band filter loss in RX band, MIN, TYP, and MAX rating are at 25°C and $V_{CC} = 3.3$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Output 1 dB gain compression	B band. max PABC input	22	23.5		dBm
		A band. max PABC input	20.5	22.5		dBm
		5150 – 5350 MHz Max PABC input, $V_{+PA} = 2.9$ V min, Other $V_{CC} = 2.7$ V min	20.5	22.5		dBm
	Output 3rd order intercept	B band	32	35		dBm
		A band	30	32.5		dBm
	Noise figure	Both bands		8		dB
	IF input return loss	Measured into 200 Ω differential	8			dB
	Mixer output return loss MX	Z = 50 Ω both bands	10			dB
	RF input return loss RF	Z = 50 Ω both bands	8			dB
	RFANT return loss	Z = 50 Ω both bands	6			dB
I_{lkg}	LO leakage at MX	B band		-35		dBm
		A band (5274-6274 MHz)		-35		dBm
	Gain flatness full band	B band		1		dB
		A band		2		dB
	Gain flatness / 22 MHz	Both bands				dB
	PA harmonics	Both bands CW at P1 dB			-20	dBc
	RFANT to RF isolation	B band		50		dB
		A band		50		dB
	PA Off Isolation RF to RFANT	In band: both bands	50			dB
	PA Turn On Time	To within 0.5 dB max power		0.2		μ s
	PA Turn Off Time	To within -20 dB max power		0.2		μ s
	PA droop	From max power after turn-on time, Maximum on duration is 200 ms			0.5	dB
	PA Bias Control Input Range (PABC)	Max Current corresponds to max PA bias state				mA

COMMON ELECTRICAL CHARACTERISTICS

MIN, TYP, and MAX ratings are at 25°C and $V_{CC} = 3.3$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	TR_SEL switch time	Gain within 0.5dB. Not Including PA ramp time		0.3	1	μ s
	AB_SEL switch time				1	μ s
	LO input power	Reference to 100 Ω differential	-1		5	dBm
	LO input return loss	Measured to 100 Ω differential at 25°C	6			
	IF port impedance	Differential		200		Ω
	LO port impedance			100		Ω

TYPICAL CHARACTERISTICS

A Band Detector Output

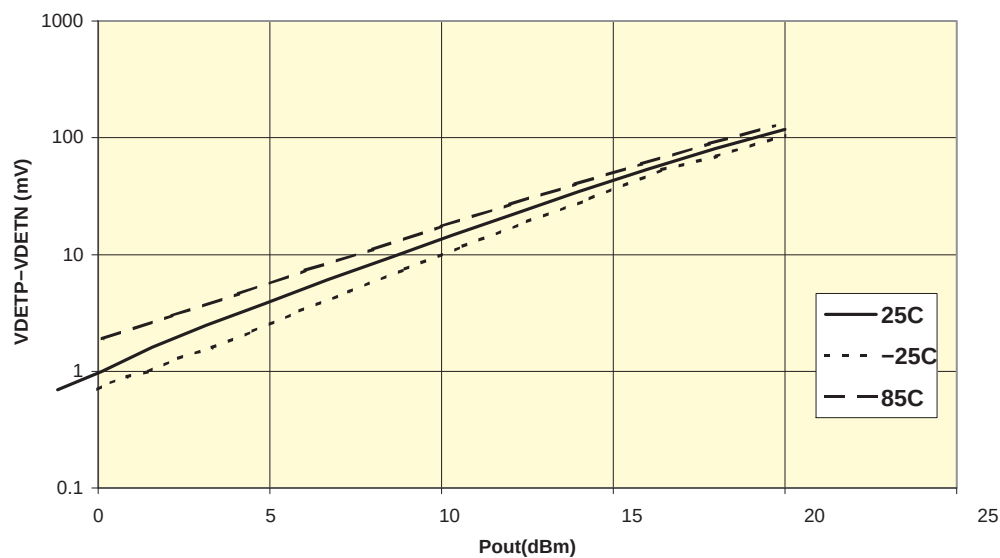


Figure 1. A Band Detector Output

B Band Detector Output



Figure 2. B Band Detector Output

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TRF2436IRTBR	OBSOLETE	VQFN	RTB	40		TBD	Call TI	Call TI		TRF 2436	
TRF2436IRTBRG4	OBSOLETE	VQFN	RTB	40		TBD	Call TI	Call TI		TRF 2436	
TRF2436IRTB	OBSOLETE	VQFN	RTB	40		TBD	Call TI	Call TI		TRF 2436	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

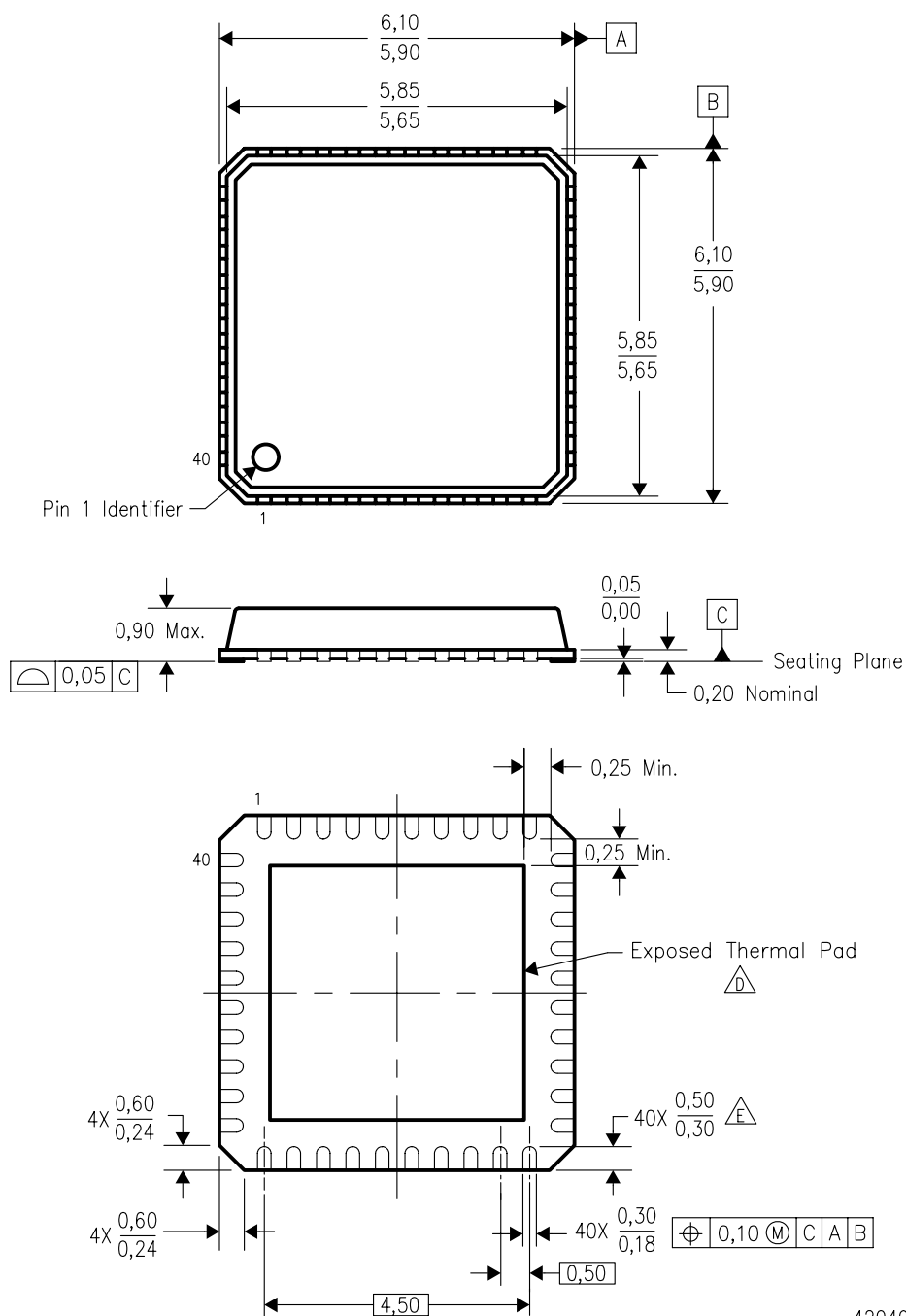
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RTB (S-PQFP-N40)

PLASTIC QUAD FLATPACK



4204967-2/E 05/07

- NOTES: A. All linear dimensions are in millimeters.
 Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.
 C. QFN (Quad Flatpack No-Lead) Package configuration.



The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions. Some products have selected lands extended past 0,50 length. See Product Data Sheet for details regarding specific land length exceptions.

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